

# 74LVC2G17-Q100

Dual non-inverting Schmitt trigger with 5 V tolerant input

Rev. 5 — 24 January 2022

Product data sheet

## 1. General description

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The 74LVC2G17-Q100 is a dual buffer with Schmitt-trigger inputs. Inputs can be driven from either 3.3 V or 5 V devices. This feature allows the use of these devices as translators in mixed 3.3 V and 5 V environments.

This device is fully specified for partial power down applications using  $I_{OFF}$ . The  $I_{OFF}$  circuitry disables the output, preventing the potentially damaging backflow current through the device when it is powered down.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

## 2. Features and benefits

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- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
  - Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Wide supply voltage range from 1.65 V to 5.5 V
- Overvoltage tolerant inputs to 5.5 V
- High noise immunity
- $\pm 24$  mA output drive ( $V_{CC} = 3.0$  V)
- CMOS low-power consumption
- Latch-up performance exceeds 250 mA
- Direct interface with TTL levels
- $I_{OFF}$  circuitry provides partial Power-down mode operation
- Complies with JEDEC standard:
  - JESD8-7 (1.65 V to 1.95 V)
  - JESD8-5 (2.3 V to 2.7 V)
  - JESD-8B/JESD36 (2.7 V to 3.6 V)
- ESD protection:
  - MIL-STD-883, method 3015 exceeds 2000 V
  - HBM JESD22-A114F exceeds 2000 V
  - MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0  $\Omega$ )

## 3. Applications

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- Wave and pulse shapers for highly noisy environments

## 4. Ordering information

Table 1. Ordering information

| Type number      | Package           |              |  | Version  |
|------------------|-------------------|--------------|--|----------|
|                  | Temperature range | Name         | Description  |          |
| 74LVC2G17GW-Q100 | -40 °C to +125 °C | TSSOP6       | plastic thin shrink small outline package; 6 leads; body width 1.25 mm | SOT363-2 |
| 74LVC2G17GV-Q100 | -40 °C to +125 °C | SC-74; TSOP6 | plastic surface-mounted package; 6 leads                               | SOT457   |

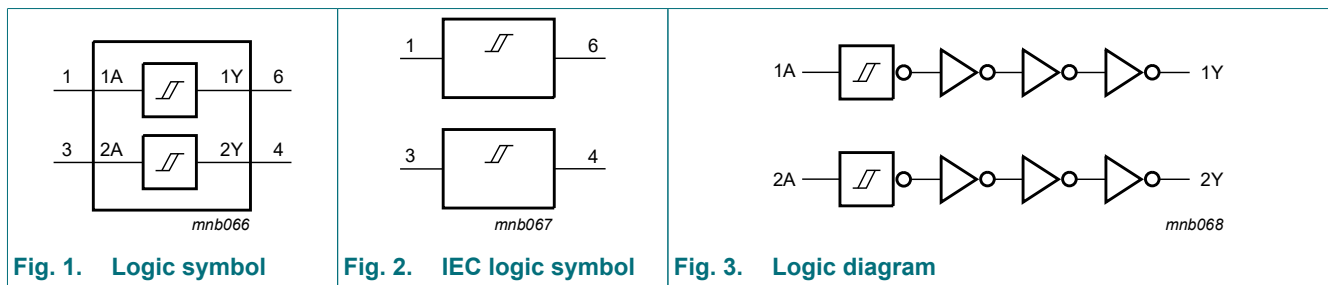
## 5. Marking

Table 2. Marking codes

| Type number      | Marking code [1] |
|------------------|------------------|
| 74LVC2G17GW-Q100 | VV               |
| 74LVC2G17GV-Q100 | VV               |

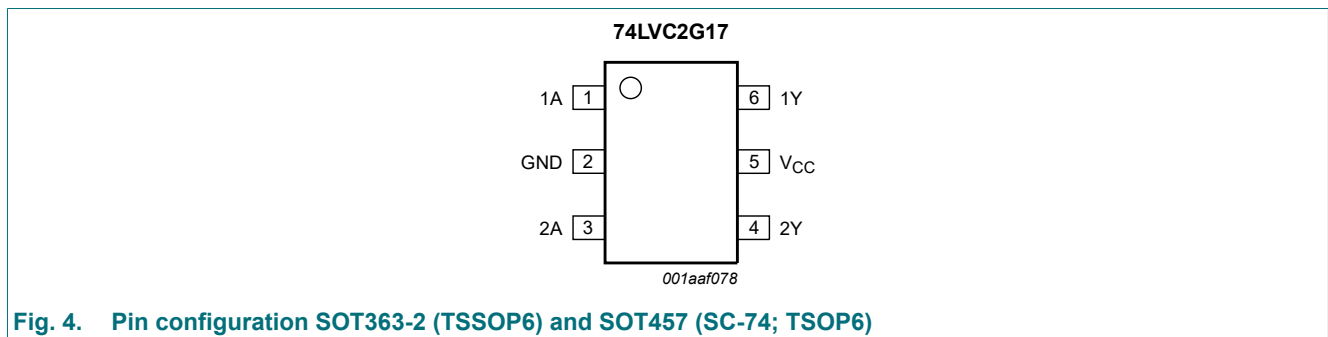
[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

## 6. Functional diagram



## 7. Pinning information

### 7.1. Pinning



## 7.2. Pin description

Table 3. Pin description

| Symbol          | Pin | Description    |
|-----------------|-----|----------------|
| 1A              | 1   | data input     |
| GND             | 2   | ground (0 V)   |
| 2A              | 3   | data input     |
| 2Y              | 4   | data output    |
| V <sub>CC</sub> | 5   | supply voltage |
| 1Y              | 6   | data output    |

## 8. Functional description

Table 4. Function table

H = HIGH voltage level; L = LOW voltage level.

| Input | Output |
|-------|--------|
| nA    | nY     |
| L     | L      |
| H     | H      |

## 9. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol           | Parameter               | Conditions                                 | Min  | Max                   | Unit |
|------------------|-------------------------|--|------|-----------------------|------|
| V <sub>CC</sub>  | supply voltage          |  | -0.5 | +6.5                  | V    |
| I <sub>IK</sub>  | input clamping current  | V <sub>I</sub> < 0 V                       | -    | -50                   | mA   |
| V <sub>I</sub>   | input voltage           | [1]  | -0.5 | +6.5                  | V    |
| I <sub>OK</sub>  | output clamping current | V <sub>O</sub> < 0 V                       | -    | -50                   | mA   |
| V <sub>O</sub>   | output voltage          | Active mode [1]                            | -0.5 | V <sub>CC</sub> + 0.5 | V    |
|                  |                         | Power-down mode; V <sub>CC</sub> = 0 V [1] | -0.5 | +6.5                  | V    |
| I <sub>O</sub>   | output current          | V <sub>O</sub> = 0 V to V <sub>CC</sub>    | -    | ±50                   | mA   |
| I <sub>CC</sub>  | supply current          |  | -    | 100                   | mA   |
| I <sub>GND</sub> | ground current          |  | -    | -100                  | mA   |
| T <sub>stg</sub> | storage temperature     |  | -65  | +150                  | °C   |
| P <sub>tot</sub> | total power dissipation | T <sub>amb</sub> = -40 °C to +125 °C [2]   | -    | 250                   | mW   |

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For SOT363-2 (TSSOP6) package: P<sub>tot</sub> derates linearly with 3.7 mW/K above 83 °C.

For SOT457 (SC-74; TSOP6) package: P<sub>tot</sub> derates linearly with 4.1 mW/K above 89 °C.

## 10. Recommended operating conditions

Table 6. Recommended operating conditions

| Symbol    | Parameter           | Conditions | Min  | Typ | Max      | Unit |
|-----------|---------------------|------------|------|-----|----------|------|
| $V_{CC}$  | supply voltage      |            | 1.65 | -   | 5.5      | V    |
| $V_I$     | input voltage       |            | 0    | -   | 5.5      | V    |
| $V_O$     | output voltage      |            | 0    | -   | $V_{CC}$ | V    |
| $T_{amb}$ | ambient temperature |            | -40  | -   | +125     | °C   |

## 11. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol   | Parameter                 | Conditions  | Min            | Typ[1]    | Max     | Unit          |
|--|---------------------------|---|----------------|-----------|---------|---------------|
| <b><math>T_{amb} = -40\text{ °C to }+85\text{ °C}</math></b> |                           |   |                |           |         |               |
| $V_{OL}$   | LOW-level output voltage  | $V_I = V_{T+}$ or $V_{T-}$  |                |           |         |               |
|  |                           | $I_O = 100\text{ }\mu\text{A}$ ; $V_{CC} = 1.65\text{ V to }5.5\text{ V}$                       | -              | -         | 0.1     | V             |
|  |                           | $I_O = 4\text{ mA}$ ; $V_{CC} = 1.65\text{ V}$  | -              | -         | 0.45    | V             |
|  |                           | $I_O = 8\text{ mA}$ ; $V_{CC} = 2.3\text{ V}$   | -              | -         | 0.3     | V             |
|  |                           | $I_O = 12\text{ mA}$ ; $V_{CC} = 2.7\text{ V}$  | -              | -         | 0.4     | V             |
|  |                           | $I_O = 24\text{ mA}$ ; $V_{CC} = 3.0\text{ V}$  | -              | -         | 0.55    | V             |
|  |                           | $I_O = 32\text{ mA}$ ; $V_{CC} = 4.5\text{ V}$  | -              | -         | 0.55    | V             |
| $V_{OH}$   | HIGH-level output voltage | $V_I = V_{T+}$ or $V_{T-}$  |                |           |         |               |
|  |                           | $I_O = -100\text{ }\mu\text{A}$ ; $V_{CC} = 1.65\text{ V to }5.5\text{ V}$                      | $V_{CC} - 0.1$ | -         | -       | V             |
|  |                           | $I_O = -4\text{ mA}$ ; $V_{CC} = 1.65\text{ V}$   | 1.2            | -         | -       | V             |
|  |                           | $I_O = -8\text{ mA}$ ; $V_{CC} = 2.3\text{ V}$  | 1.9            | -         | -       | V             |
|  |                           | $I_O = -12\text{ mA}$ ; $V_{CC} = 2.7\text{ V}$   | 2.2            | -         | -       | V             |
|  |                           | $I_O = -24\text{ mA}$ ; $V_{CC} = 3.0\text{ V}$   | 2.3            | -         | -       | V             |
|  |                           | $I_O = -32\text{ mA}$ ; $V_{CC} = 4.5\text{ V}$   | 3.8            | -         | -       | V             |
| $I_I$  | input leakage current     | $V_I = 5.5\text{ V or GND}$ ; $V_{CC} = 5.5\text{ V}$   | -              | $\pm 0.1$ | $\pm 1$ | $\mu\text{A}$ |
| $I_{OFF}$  | power-off leakage current | $V_I$ or $V_O = 5.5\text{ V}$ ; $V_{CC} = 0\text{ V}$   | -              | $\pm 0.1$ | $\pm 2$ | $\mu\text{A}$ |
| $I_{CC}$   | supply current            | $V_I = V_{CC}$ or $\text{GND}$ ; $I_O = 0\text{ A}$ ; $V_{CC} = 5.5\text{ V}$                   | -              | 0.1       | 4       | $\mu\text{A}$ |
| $\Delta I_{CC}$  | additional supply current | $V_I = V_{CC} - 0.6\text{ V}$ ; $I_O = 0\text{ A}$ ;<br>$V_{CC} = 2.3\text{ V to }5.5\text{ V}$ | -              | 5         | 500     | $\mu\text{A}$ |
| $C_I$  | input capacitance         |   | -              | 3.5       | -       | pF            |

## Dual non-inverting Schmitt trigger with 5 V tolerant input

| Symbol                                     | Parameter                 | Conditions  | Min                   | Typ[1] | Max  | Unit |
|--|---------------------------|---|-----------------------|--------|------|------|
| <b>T<sub>amb</sub> = -40 °C to +125 °C</b> |                           |   |                       |        |      |      |
| V <sub>OL</sub>                            | LOW-level output voltage  | V <sub>I</sub> = V <sub>T+</sub> or V <sub>T-</sub>   |                       |        |      |      |
|  |                           | I <sub>O</sub> = 100 μA; V <sub>CC</sub> = 1.65 V to 5.5 V  | -                     | -      | 0.1  | V    |
|  |                           | I <sub>O</sub> = 4 mA; V <sub>CC</sub> = 1.65 V   | -                     | -      | 0.70 | V    |
|  |                           | I <sub>O</sub> = 8 mA; V <sub>CC</sub> = 2.3 V  | -                     | -      | 0.45 | V    |
|  |                           | I <sub>O</sub> = 12 mA; V <sub>CC</sub> = 2.7 V   | -                     | -      | 0.60 | V    |
|  |                           | I <sub>O</sub> = 24 mA; V <sub>CC</sub> = 3.0 V   | -                     | -      | 0.80 | V    |
| V <sub>OH</sub>                            | HIGH-level output voltage | V <sub>I</sub> = V <sub>T+</sub> or V <sub>T-</sub>   |                       |        |      |      |
|  |                           | I <sub>O</sub> = -100 μA; V <sub>CC</sub> = 1.65 V to 5.5 V   | V <sub>CC</sub> - 0.1 | -      | -    | V    |
|  |                           | I <sub>O</sub> = -4 mA; V <sub>CC</sub> = 1.65 V  | 0.95                  | -      | -    | V    |
|  |                           | I <sub>O</sub> = -8 mA; V <sub>CC</sub> = 2.3 V   | 1.7                   | -      | -    | V    |
|  |                           | I <sub>O</sub> = -12 mA; V <sub>CC</sub> = 2.7 V  | 1.9                   | -      | -    | V    |
|  |                           | I <sub>O</sub> = -24 mA; V <sub>CC</sub> = 3.0 V  | 2.0                   | -      | -    | V    |
| I <sub>I</sub>                             | input leakage current     | V <sub>I</sub> = 5.5 V or GND; V <sub>CC</sub> = 5.5 V  | -                     | ±0.1   | ±1   | μA   |
|  |                           | V <sub>I</sub> or V <sub>O</sub> = 5.5 V; V <sub>CC</sub> = 0 V                                     | -                     | -      | ±2   | μA   |
| I <sub>OFF</sub>                           | power-off leakage current | V <sub>I</sub> or V <sub>O</sub> = 5.5 V; V <sub>CC</sub> = 0 V                                     | -                     | -      | ±2   | μA   |
| I <sub>CC</sub>                            | supply current            | V <sub>I</sub> = V <sub>CC</sub> or GND; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 5.5 V              | -                     | -      | 4    | μA   |
| ΔI <sub>CC</sub>                           | additional supply current | V <sub>I</sub> = V <sub>CC</sub> - 0.6 V; I <sub>O</sub> = 0 A;<br>V <sub>CC</sub> = 2.3 V to 5.5 V | -                     | -      | 500  | μA   |

[1] All typical values are measured at V<sub>CC</sub> = 3.3 V and T<sub>amb</sub> = 25 °C.

## 12. Dynamic characteristics

**Table 8. Dynamic characteristics**

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 6.

| Symbol          | Parameter                     | Conditions   | -40 °C to +85 °C |        |      | -40 °C to +125 °C |      | Unit |
|-----------------|-------------------------------|--|------------------|--------|------|-------------------|------|------|
|                 |                               |  | Min              | Typ[1] | Max  | Min               | Max  |      |
| t <sub>pd</sub> | propagation delay             | nA to nY; see Fig. 5 [2]   |                  |        |      |                   |      |      |
|                 |                               | V <sub>CC</sub> = 1.65 V to 1.95 V   | 1.5              | 5.6    | 10.5 | 1.5               | 13.1 | ns   |
|                 |                               | V <sub>CC</sub> = 2.3 V to 2.7 V   | 1.0              | 3.7    | 6.5  | 1.0               | 8.5  | ns   |
|                 |                               | V <sub>CC</sub> = 2.7 V  | 1.0              | 3.8    | 6.5  | 1.0               | 8.5  | ns   |
|                 |                               | V <sub>CC</sub> = 3.0 V to 3.6 V   | 1.0              | 3.6    | 5.7  | 1.0               | 7.1  | ns   |
|                 |                               | V <sub>CC</sub> = 4.5 V to 5.5 V   | 1.0              | 2.7    | 4.3  | 1.0               | 5.4  | ns   |
| C <sub>PD</sub> | power dissipation capacitance | per buffer; V <sub>CC</sub> = 3.3 V; V <sub>I</sub> = GND to V <sub>CC</sub> [3] | -                | 16.3   | -    | -                 | -    | pF   |

[1] Typical values are measured at T<sub>amb</sub> = 25 °C and V<sub>CC</sub> = 1.8 V, 2.5 V, 2.7 V, 3.3 V and 5.0 V respectively.

[2] t<sub>pd</sub> is the same as t<sub>PLH</sub> and t<sub>PHL</sub>.

[3] C<sub>PD</sub> is used to determine the dynamic power dissipation (P<sub>D</sub> in μW).

$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum(C_L \times V_{CC}^2 \times f_o)$  where:

f<sub>i</sub> = input frequency in MHz;

f<sub>o</sub> = output frequency in MHz;

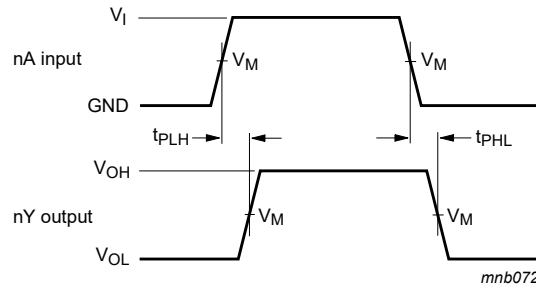
C<sub>L</sub> = output load capacitance in pF;

V<sub>CC</sub> = supply voltage in V;

N = number of inputs switching;

$\sum(C_L \times V_{CC}^2 \times f_o)$  = sum of outputs.

12.1. Waveforms and test circuit



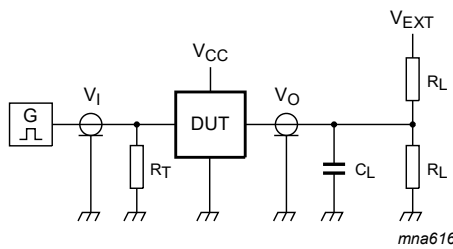
Measurement points are given in [Table 9](#).

$V_{OL}$  and  $V_{OH}$  are typical output voltage drop that occur with the output load.

Fig. 5. The input (nA) to output (nY) propagation delays and the output transition times

Table 9. Measurement points

| Supply voltage   | Input               | Output              |
|------------------|---------------------|---------------------|
| $V_{CC}$         | $V_M$               | $V_M$               |
| 1.65 V to 1.95 V | $0.5 \times V_{CC}$ | $0.5 \times V_{CC}$ |
| 2.3 V to 2.7 V   | $0.5 \times V_{CC}$ | $0.5 \times V_{CC}$ |
| 2.7 V            | 1.5 V               | 1.5 V               |
| 3.0 V to 3.6 V   | 1.5 V               | 1.5 V               |
| 4.5 V to 5.5 V   | $0.5 \times V_{CC}$ | $0.5 \times V_{CC}$ |



Measurement points are given in [Table 10](#).

Definitions for test circuit:

$R_L$  = Load resistance.

$C_L$  = Load capacitance including jig and probe capacitance.

$R_T$  = Termination resistance should be equal to output impedance  $Z_o$  of the pulse generator.

$V_{EXT}$  = External voltage for measuring switching times.

Fig. 6. Test circuit for measuring switching times

Table 10. Test data

| Supply voltage   | Input    | Load          |       | $V_{EXT}$          |      |
|------------------|----------|---------------|-------|--------------------|------|
| $V_{CC}$         | $V_I$    | $t_r, t_f$    | $C_L$ | $R_L$              |      |
|                  |          |               |       | $t_{PLH}, t_{PHL}$ |      |
| 1.65 V to 1.95 V | $V_{CC}$ | $\leq 2.0$ ns | 30 pF | 1 k $\Omega$       | open |
| 2.3 V to 2.7 V   | $V_{CC}$ | $\leq 2.0$ ns | 30 pF | 500 $\Omega$       | open |
| 2.7 V            | 2.7 V    | $\leq 2.5$ ns | 50 pF | 500 $\Omega$       | open |
| 3.0 V to 3.6 V   | 2.7 V    | $\leq 2.5$ ns | 50 pF | 500 $\Omega$       | open |
| 4.5 V to 5.5 V   | $V_{CC}$ | $\leq 2.5$ ns | 50 pF | 500 $\Omega$       | open |

### 13. Transfer characteristics

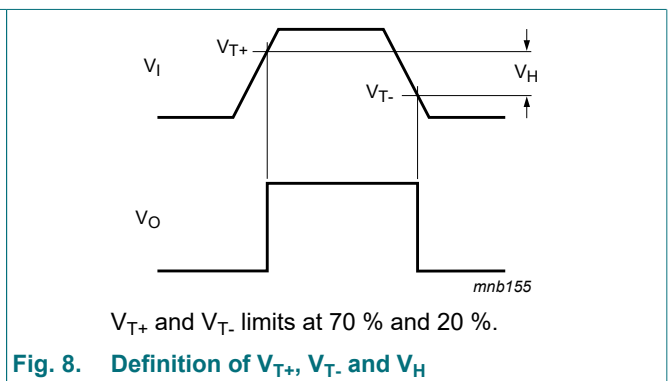
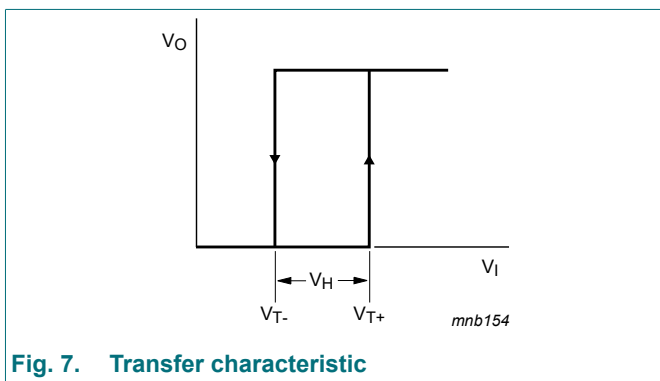
**Table 11. Transfer characteristics**

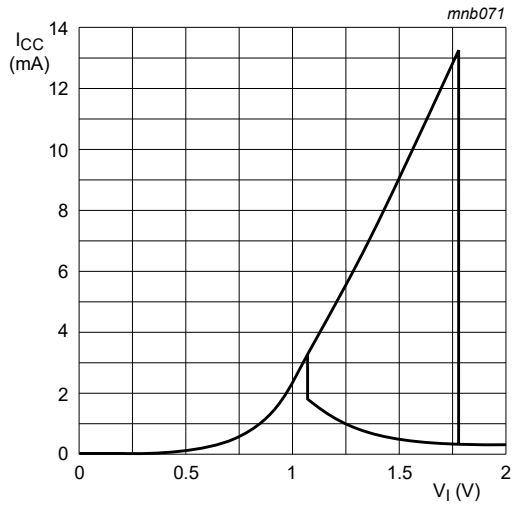
At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

| Symbol          | Parameter                        | Conditions   | -40 °C to +85 °C |        |      | -40 °C to +125 °C |      | Unit |
|-----------------|----------------------------------|--|------------------|--------|------|-------------------|------|------|
|                 |                                  |  | Min              | Typ[1] | Max  | Min               | Max  |      |
| V <sub>T+</sub> | positive-going threshold voltage | see <a href="#">Fig. 7</a> and <a href="#">Fig. 8</a>  |                  |        |      |                   |      |      |
|                 |                                  | V <sub>CC</sub> = 1.8 V  | 0.70             | 1.10   | 1.50 | 0.70              | 1.70 | V    |
|                 |                                  | V <sub>CC</sub> = 2.3 V  | 1.00             | 1.40   | 1.80 | 1.00              | 2.00 | V    |
|                 |                                  | V <sub>CC</sub> = 3.0 V  | 1.30             | 1.76   | 2.20 | 1.30              | 2.40 | V    |
|                 |                                  | V <sub>CC</sub> = 4.5 V  | 1.90             | 2.47   | 3.10 | 1.90              | 3.30 | V    |
| V <sub>T-</sub> | negative-going threshold voltage | see <a href="#">Fig. 7</a> and <a href="#">Fig. 8</a>  |                  |        |      |                   |      |      |
|                 |                                  | V <sub>CC</sub> = 1.8 V  | 0.25             | 0.61   | 0.90 | 0.25              | 1.10 | V    |
|                 |                                  | V <sub>CC</sub> = 2.3 V  | 0.40             | 0.80   | 1.15 | 0.40              | 1.35 | V    |
|                 |                                  | V <sub>CC</sub> = 3.0 V  | 0.60             | 1.04   | 1.50 | 0.60              | 1.70 | V    |
|                 |                                  | V <sub>CC</sub> = 4.5 V  | 1.00             | 1.55   | 2.00 | 1.00              | 2.20 | V    |
| V <sub>H</sub>  | hysteresis voltage               | (V <sub>T+</sub> - V <sub>T-</sub> ); see <a href="#">Fig. 7</a> , <a href="#">Fig. 8</a> and <a href="#">Fig. 9</a> |                  |        |      |                   |      |      |
|                 |                                  | V <sub>CC</sub> = 1.8 V  | 0.15             | 0.49   | 1.00 | 0.15              | 1.20 | V    |
|                 |                                  | V <sub>CC</sub> = 2.3 V  | 0.25             | 0.60   | 1.10 | 0.25              | 1.30 | V    |
|                 |                                  | V <sub>CC</sub> = 3.0 V  | 0.40             | 0.73   | 1.20 | 0.40              | 1.40 | V    |
|                 |                                  | V <sub>CC</sub> = 4.5 V  | 0.60             | 0.92   | 1.50 | 0.60              | 1.70 | V    |
|                 |                                  | V <sub>CC</sub> = 5.5 V  | 0.70             | 1.02   | 1.70 | 0.70              | 1.90 | V    |

[1] All typical values are measured at T<sub>amb</sub> = 25 °C.

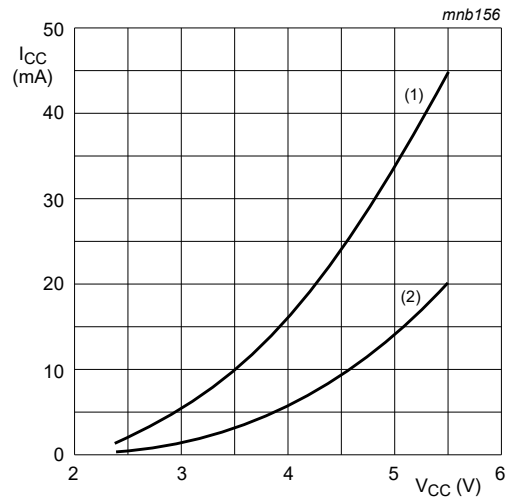
#### 13.1. Waveforms transfer characteristics





$V_{CC} = 3.0$  V.

Fig. 9. Typical transfer characteristic



(1) Positive-going edge

(2) Negative-going edge

Linear change of  $V_I$  between 0.8 V to 2.0 V. All values given are typical unless otherwise specified.

Fig. 10. Average  $I_{CC}$  as a function of  $V_{CC}$



14. Package outline

TSSOP6: plastic thin shrink small outline package; 6 leads; body width 1.25 mm

SOT363-2

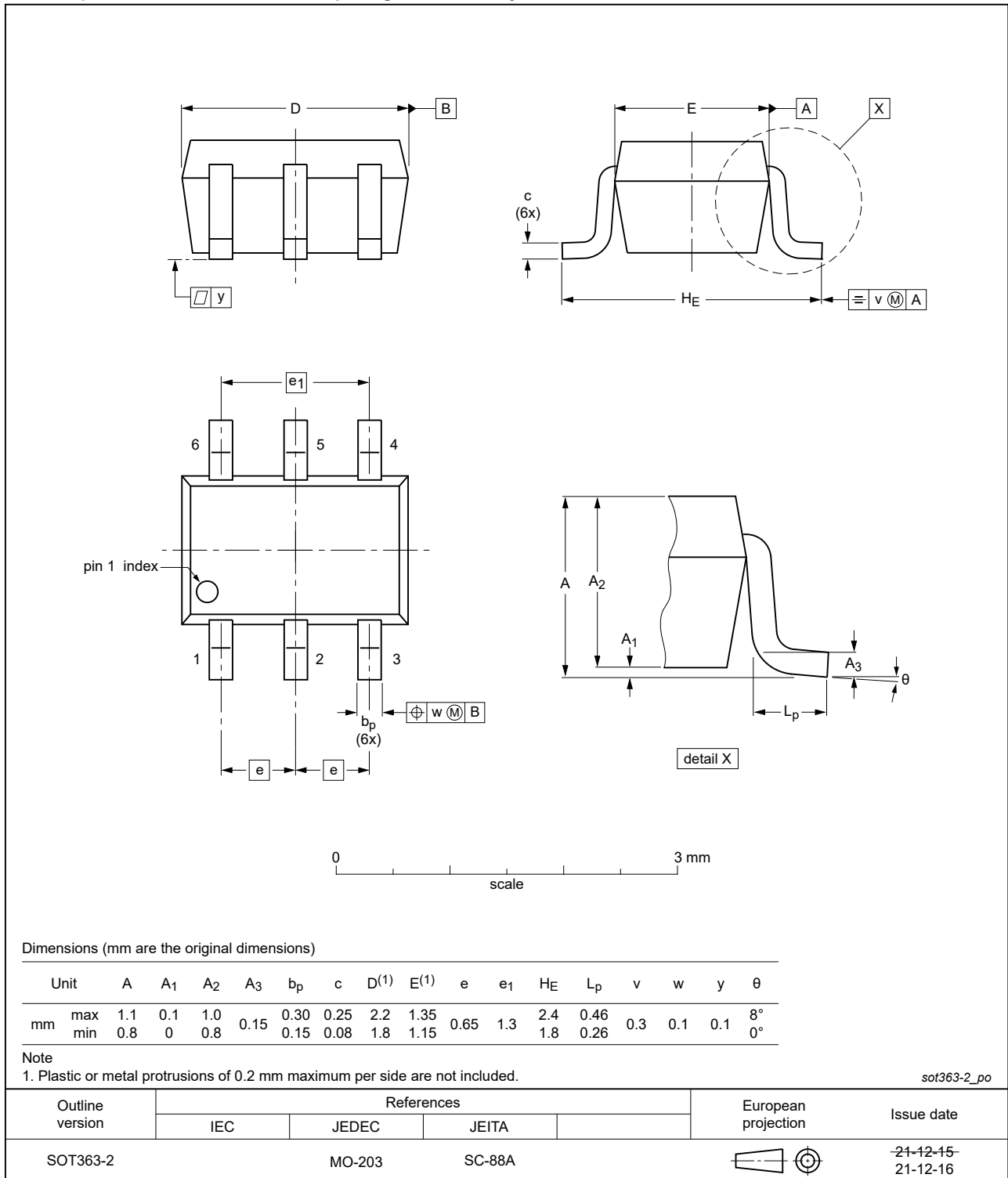


Fig. 11. Package outline SOT363-2 (TSSOP6)

Plastic, surface-mounted package (SC-74; TSOP6); 6 leads

SOT457

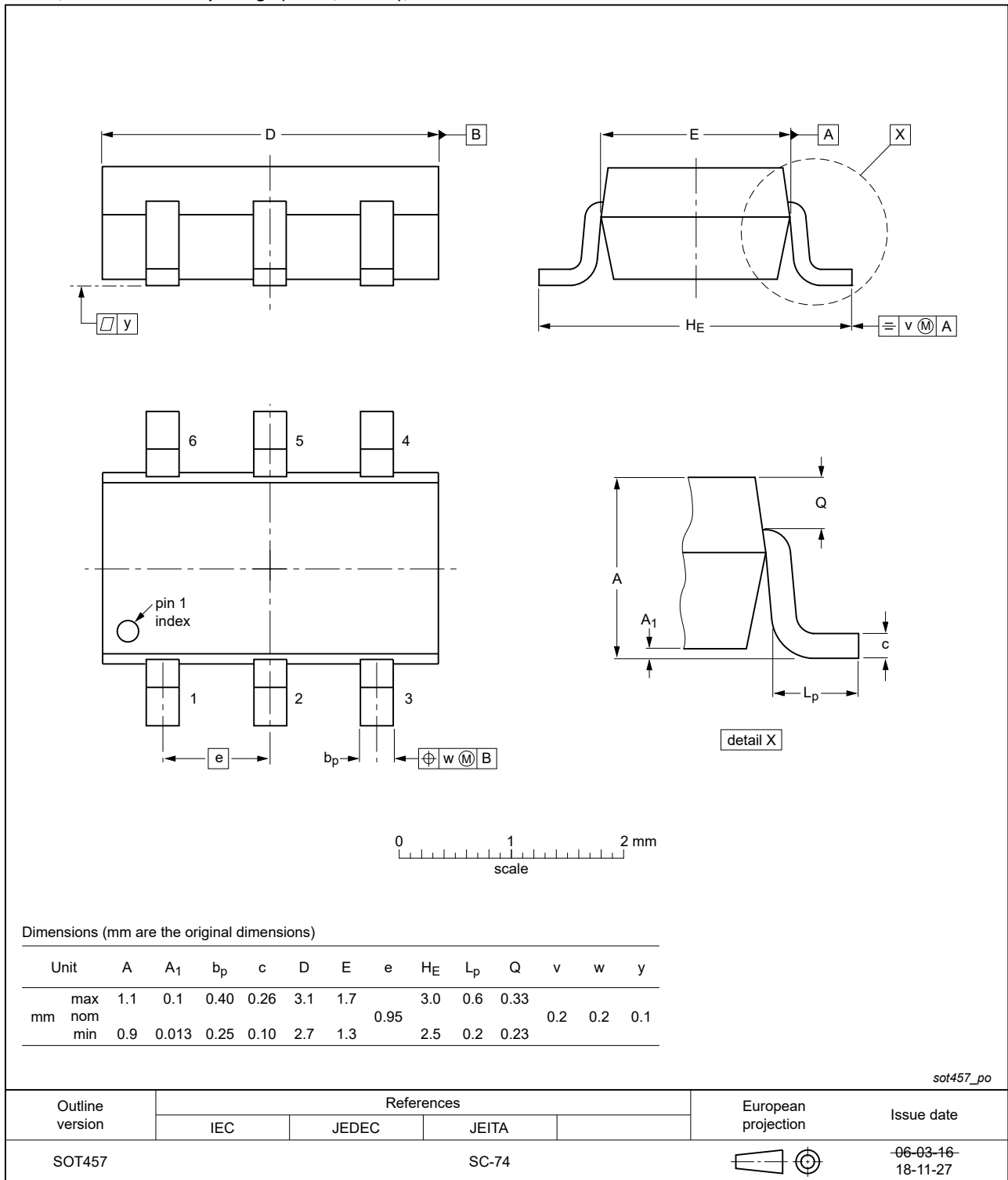


Fig. 12. Package outline SOT457 (SC-74; TSOP6)

## 15. Abbreviations

Table 12. Abbreviations

| Acronym | Description                             |
|---------|---|
| CMOS    | Complementary Metal-Oxide Semiconductor |
| DUT     | Device Under Test                       |
| ESD     | ElectroStatic Discharge                 |
| HBM     | Human Body Model                        |
| MIL     | Military                                |
| MM      | Machine Model                           |
| TTL     | Transistor-Transistor Logic             |

## 16. Revision history

Table 13. Revision history

| Document ID        | Release date   | Data sheet status  | Change notice | Supersedes         |
|--------------------|--|--------------------|---------------|--------------------|
| 74LVC2G17_Q100 v.5 | 20220124   | Product data sheet | -             | 74LVC2G17_Q100 v.4 |
| Modifications:     | <ul style="list-style-type: none"> <li>Package SOT363 (SC-88) changed to SOT363-2 (TSSOP6).</li> </ul>   |                    |               |                    |
| 74LVC2G17_Q100 v.4 | 20210621   | Product data sheet | -             | 74LVC2G17_Q100 v.3 |
| Modifications:     | <ul style="list-style-type: none"> <li>The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> <li><a href="#">Section 1</a> and <a href="#">Section 2</a> updated.</li> <li><a href="#">Section 9</a>: Derating values for <math>P_{tot}</math> total power dissipation updated.</li> <li><a href="#">Fig. 12</a>: Package outline drawing SOT457 (SC-74; TSOP6) updated.</li> </ul> |                    |               |                    |
| 74LVC2G17_Q100 v.3 | 20161214   | Product data sheet | -             | 74LVC2G17_Q100 v.2 |
| Modifications:     | <ul style="list-style-type: none"> <li><a href="#">Table 7</a>: The maximum limits for leakage current and supply current have changed.</li> </ul>   |                    |               |                    |
| 74LVC2G17_Q100 v.2 | 20130502   | Product data sheet | -             | 74LVC2G17_Q100 v.1 |
| Modifications:     | <ul style="list-style-type: none"> <li><a href="#">Table 3</a>: the description of pin 6 changed from data input to data output.</li> </ul>  |                    |               |                    |
| 74LVC2G17_Q100 v.1 | 20120807   | Product data sheet | -             | -                  |

## 17. Legal information

### Data sheet status

| Document status [1][2]         | Product status [3] | Definition  |
|--------------------------------|--------------------|---|
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| Preliminary [short] data sheet | Qualification      | This document contains data from the preliminary specification.                       |
| Product [short] data sheet     | Production         | This document contains the product specification.                                     |

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- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <https://www.nexperia.com>.

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